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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT3029R

Silicon N/P Channel Power MOS FET Power Switching

REJ03G1597-0600 Rev.6.00 Oct 16, 2007

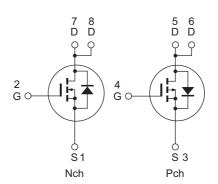
Features

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

Outline

RENESAS Package code: PRSP0008DD-D (Package name: SOP-8<FP-8DAV>)





1, 3 Source 2, 4 Gate

5, 6, 7, 8 Drain

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

ltem	Symbol	Ra	Unit	
item	Symbol	Nch	Pch	Offic
Drain to source voltage	V_{DSS}	30	-30	V
Gate to source voltage	V_{GSS}	±20	-20/+10	V
Drain current	I _D	6	-6	Α
Drain peak current	I _{D(pulse)} Note1	48	-48	Α
Body-drain diode reverse drain current	I _{DR}	6	-6	Α
Channel dissipation	Pch Note2	,	1.3	W
Channel dissipation	Pch Note3	Pch Note3 2.0		W
Channel temperature	Tch	1	150	°C
Storage temperature	Tstg	-55 t	o +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

- 2. 1 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s
- 3. 2 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), $PW \le 10s$

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

• N Channel

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	1	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	1	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0		2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	1	27	34	mΩ	$I_D = 3 A, V_{GS} = 10 V^{Note4}$
resistance	R _{DS(on)}	1	40	58	mΩ	$I_D = 3 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	6	10	_	S	$I_D = 3 A, V_{DS} = 10 V^{Note4}$
Input capacitance	Ciss		410	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	110	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	41	_	pF	f = 1 MHz
Total gate charge	Qg	_	3.1	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs	_	1.1	_	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd	_	1.1	_	nC	I _D = 6 A
Turn-on delay time	t _{d(on)}	_	5.4	_	ns	$V_{GS} = 10 \text{ V}, I_D = 3 \text{ A}$
Rise time	t _r	_	10	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t _{d(off)}	_	36	_	ns	$R_L = 3.33 \Omega$
Fall time	t _f	_	3.0	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.84	1.10	V	$IF = 6 A$, $V_{GS} = 0$ Note4
Body-drain diode reverse recovery	t _{rr}	_	20	_	ns	IF = 6 A, V _{GS} = 0
time						$di_F/dt = 100 A/ \mu s$

Notes: 4. Pulse test

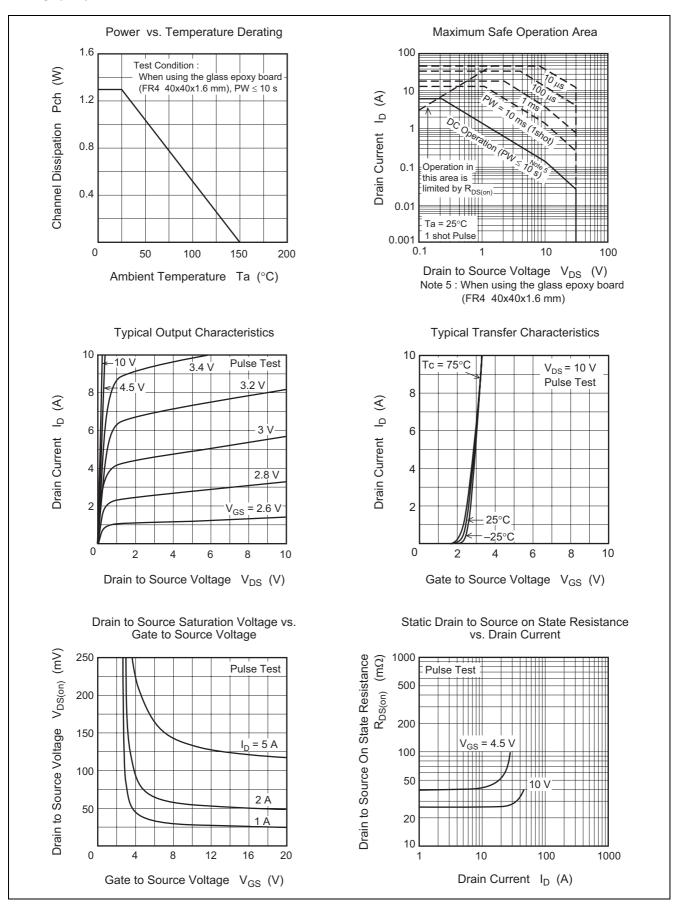
• P Channel

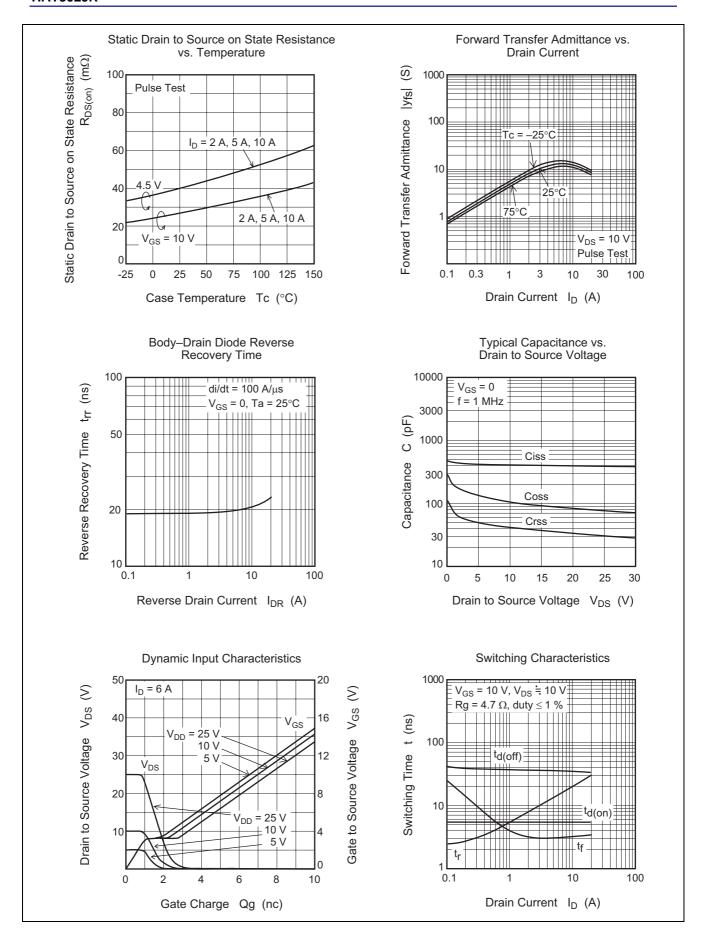
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	-30	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = -20,+10 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.5	V	$V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	25	32	mΩ	$I_D = -3 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	36	53	mΩ	$I_D = -3 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	6	10	_	S	$I_D = -3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	1330	_	pF	V _{DS} = -10 V
Output capacitance	Coss	_	215	_	pF	V _{GS} = 0 f = 1MHz
Reverse transfer capacitance	Crss	_	155	_	pF	
Total gate charge	Qg	_	11.5	_	nC	V _{DD} = -10 V
Gate to source charge	Qgs	_	3.2	_	nC	$V_{GS} = -4.5 \text{ V}$
Gate to drain charge	Qgd	_	4.4	_	nC	$I_D = -6 A$
Turn-on delay time	t _{d(on)}	_	18	_	ns	$V_{GS} = -10 \text{ V}, I_D = -3 \text{ A}$
Rise time	t _r	_	19	_	ns	$V_{DD} \cong -10 \text{ V}$ $R_L = 3.33 \Omega$ $R_g = 4.7 \Omega$
Turn-off delay time	t _{d(off)}	_	47	_	ns	
Fall time	t _f	_	8	_	ns	
Body-drain diode forward voltage	V_{DF}	_	-0.84	-1.10	V	$IF = -6 A$, $V_{GS} = 0$ Note4
Body-drain diode reverse	t _{rr}	_	20	_	ns	$IF = -6 A, V_{GS} = 0$
recovery time						$di_F/dt = 100A/\mu s$

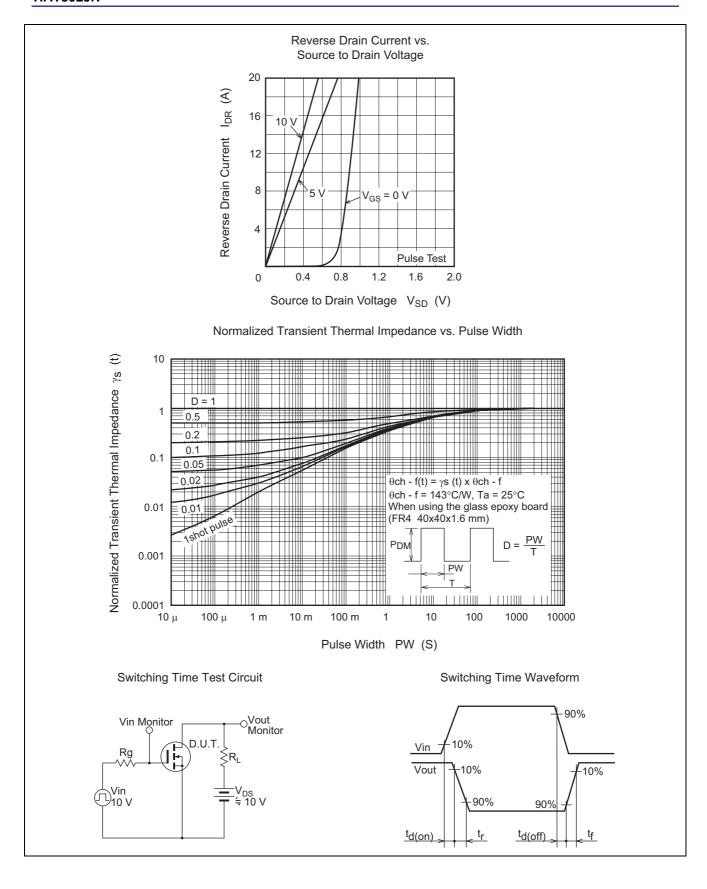
Notes: 4. Pulse test

Main Characteristics

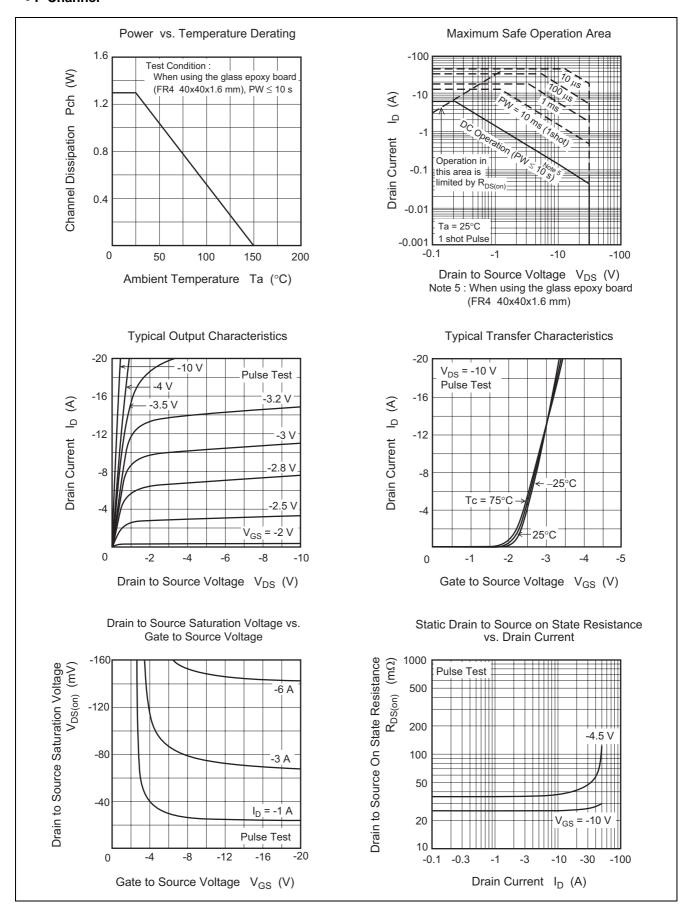
• N Channel

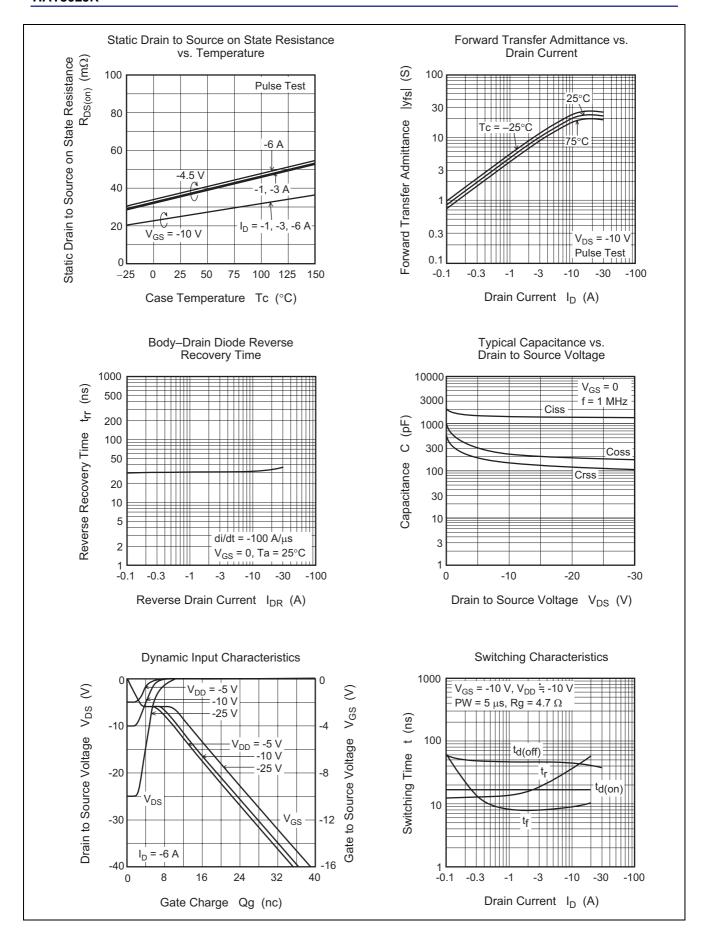


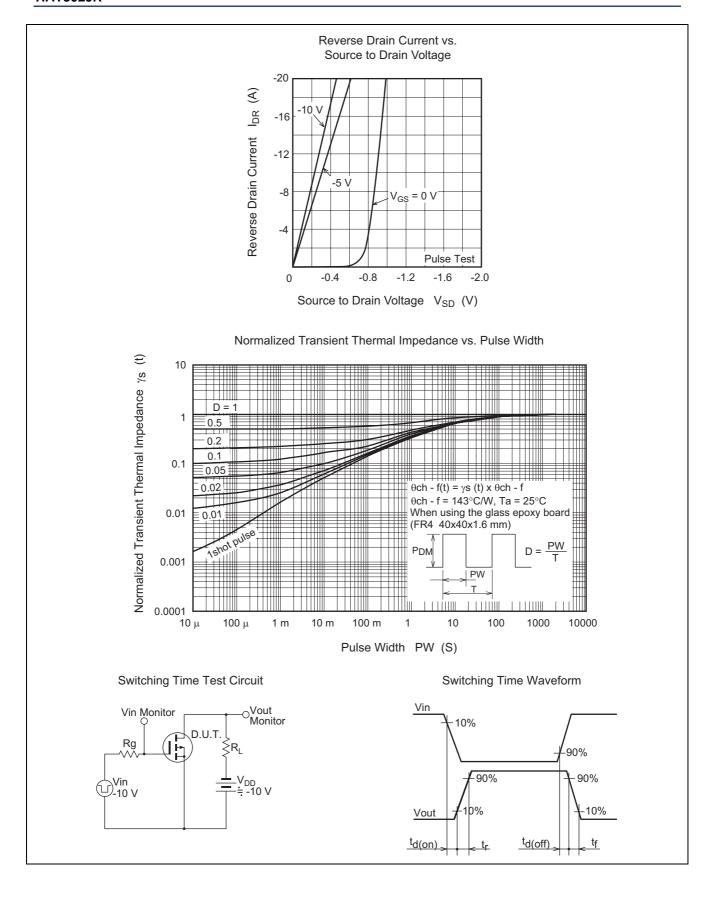




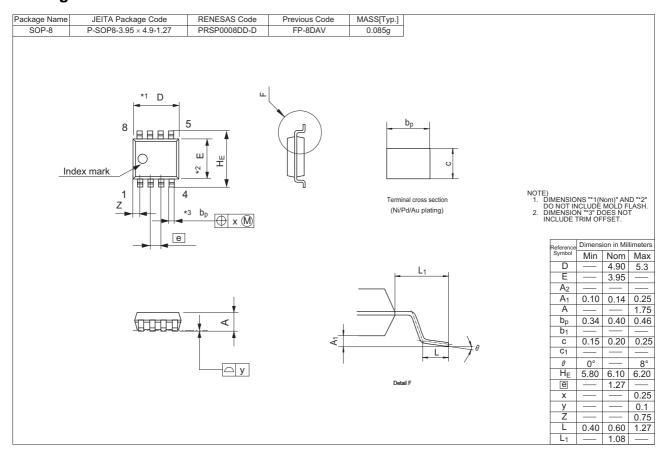
• P Channel







Package Dimensions



Ordering Information

Part Name Quantity		Shipping Container		
HAT3029R-EL-E	2500 pcs	Taping		

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